

MICROSTRUCTURE SIMULATION MODELS FOR THE GROWTH OF INTERMEDIATE PHASES WITH LOW SOLUBILITY

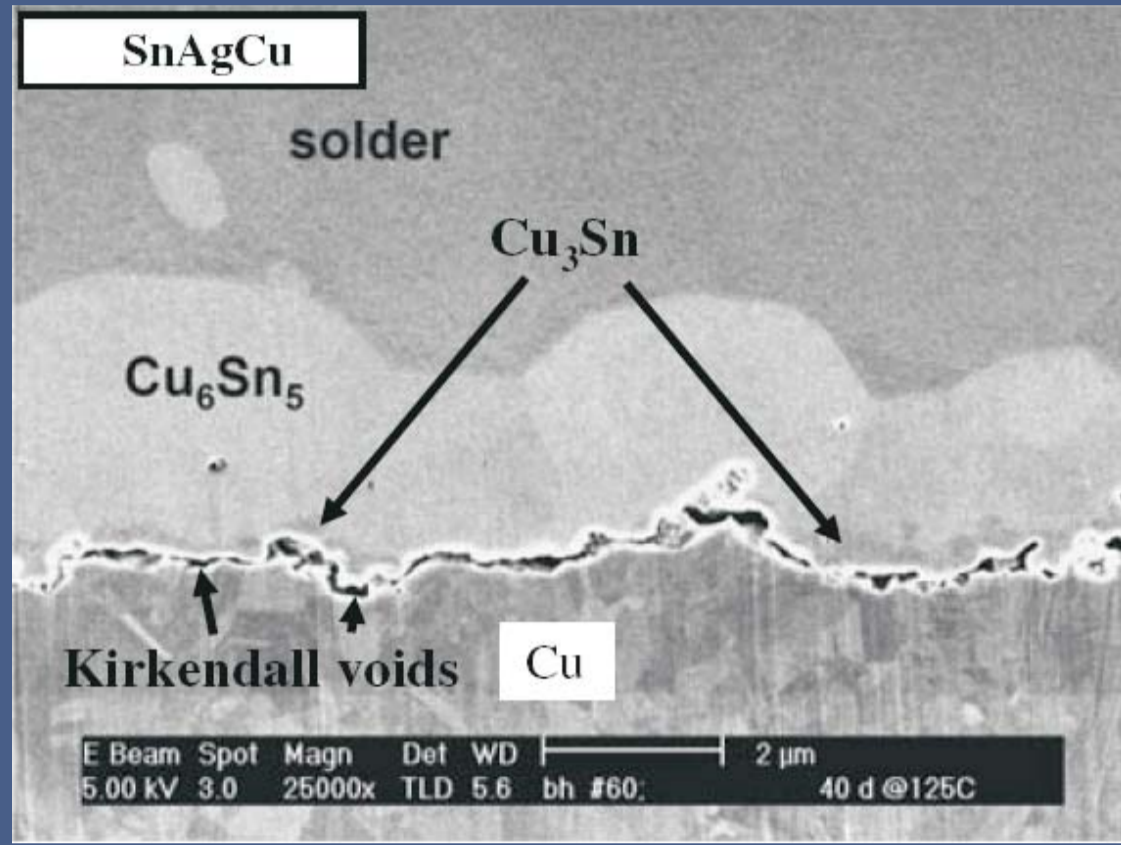


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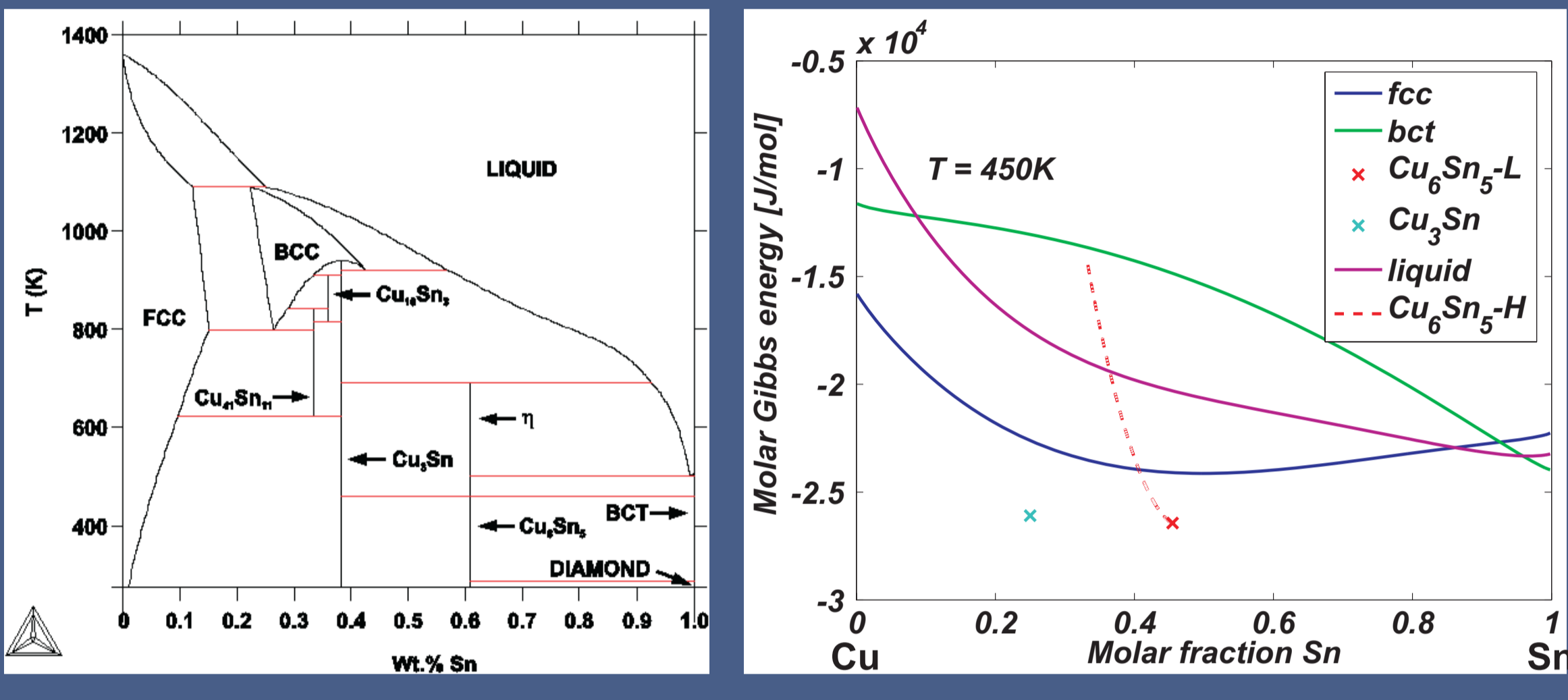
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Motivation

Reactive growth of intermediate phases with low solubility is important for many applications, for example intermetallic compound (IMC) growth in solder joints, growth of silicide layers and oxidation.



In phase diagrams and CALPHAD Gibbs energy models, phases with low solubility are often treated as stoichiometric or with a very limited composition domain. Microstructure and diffusion simulations require however information on the composition dependence of the Gibbs energy, also in metastable regions.



Phase field model for multi-phase systems[1]

$x_{Sn,eq} = 0.05$
 $\eta_{(Cu)_i}$

$x_{Sn,eq} = 0.25$
 $\eta_{Cu3Sn,i}$

$x_{Sn,eq} = 0.45$
 $\eta_{Cu6Sn5,i}$

$x_{Sn,eq} = 0.999$
 $\eta_{(Sn)_i}$

Phases and grains

$$\vec{\eta} = (\eta_{(Cu)_1}(r,t), \eta_{(Cu)_2}, \dots, \eta_{(Sn)_1}, \dots, \eta_{Cu6Sn5,1}, \dots)$$

Composition

Binary Cu-Sn: $\vec{x} = (x_{Cu}(r,t), x_{Sn}(r,t))$, $x_{Cu}(r,t) = 1 - x_{Sn}(r,t)$

Ternary Ag-Cu-Sn: $\vec{x} = (x_{Cu}(r,t), x_{Sn}(r,t), x_{Ag}(r,t))$, $x_{Ag}(r,t) = 1 - x_{Cu}(r,t) - x_{Sn}(r,t)$

Phase-field variables

Energy functional

$$F_{tot} = \int [f_{int}(\eta_{p,i}, \nabla \eta_{p,i}) + f_{bulk}(\eta_{p,i}, x_k)] dV$$

with f_{int} from [2] and f_{bulk} of the form

$$f_{bulk} = \sum_{\rho} \phi_{\rho} f^{\rho}(x_k^{\rho}) = \sum_{\rho} \phi_{\rho} \frac{G_m^{\rho}(x_k^{\rho})}{V_m}$$

Diffusion

$$\frac{\partial x_k}{\partial t} = \nabla \cdot \left[\sum_l \left[\left(\sum_{\rho} \phi_{\rho} M_{kl}^{\rho} \right) \nabla \left(\frac{\partial f^{\rho}}{\partial x_l^{\rho}} \right) \right] \right]$$

$$\nabla \cdot \left[\sum_l \left[\left(\sum_{\rho} \phi_{\rho} \frac{M_{kl}^{\rho}}{V_m} \right) \nabla (\mu_l - \mu_{dep}) \right] \right]$$

Phase boundary movement

$$\frac{\partial \eta_{p,i}}{\partial t} = -L \frac{\delta F(\eta_{\sigma,i}, x_k)}{\delta \eta_{p,i}}$$

Interpolation/phase fraction[1]

$$\phi_{\rho} = \frac{\sum_i \eta_{\rho,i}}{\sum_{\sigma} \sum_i \eta_{\sigma,i}}$$

Phase compositions[3]

$$\begin{cases} \frac{\partial f^{\beta}(x_k^{\beta})}{\partial x_k^{\beta}} = \frac{\partial f^{\alpha}(x_k^{\alpha})}{\partial x_k^{\alpha}} \\ x_k = \sum_{\rho} \phi_{\rho} x_k^{\rho} \end{cases}$$

Diffusion mobilities

$$M_{kl}^{\rho} = \frac{D_{kl}^{\rho}}{\partial^2 f^{\rho}} = \frac{V_m D_{kl}^{\rho}}{\partial^2 G^{\rho}}$$

4 Gibbs energy models

Stoichiometric

$$f_{bulk} = \sum_{\rho \neq stoich} \phi_{\rho} \frac{G_m^{\rho}(x_k^{\rho})}{V_m} + \phi_{stoich} \frac{G_m^{stoich}}{V_m}$$

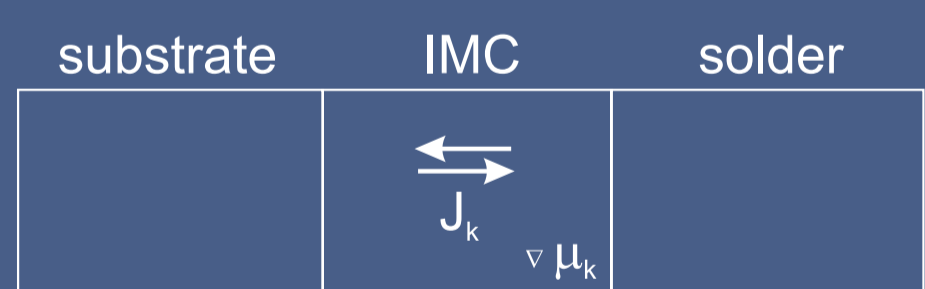
$$\frac{\partial f^{\rho}(x_k^{\rho})}{\partial x_k^{\rho}} = \frac{\partial f^{\sigma}(x_k^{\sigma})}{\partial x_k^{\sigma}}$$

$\forall k, \rho \neq \sigma$ solution phases

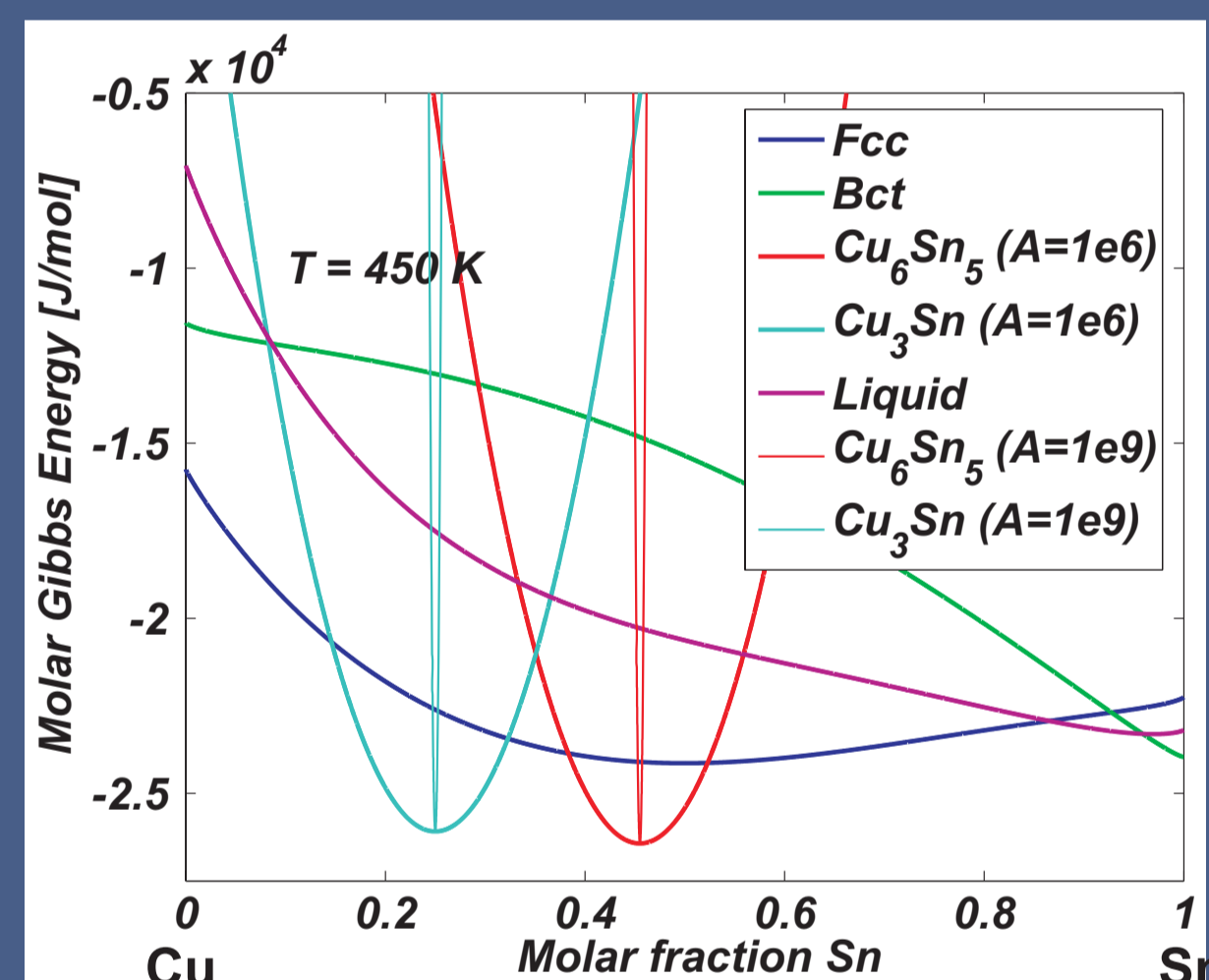
$$x_k - x_k^{stoich} = \sum_{\rho \neq sol} \phi_{\rho} (x_k^{\rho} - x_k^{stoich}), \forall k$$

$$D_{kl}^{stoich} = M_{kl}^{stoich} = 0$$

Diffusion through IMC phase however requires $G^{\rho}(x_k)$ to model $\text{grad}(\mu_k)$, the driving force for diffusion



Parabolic



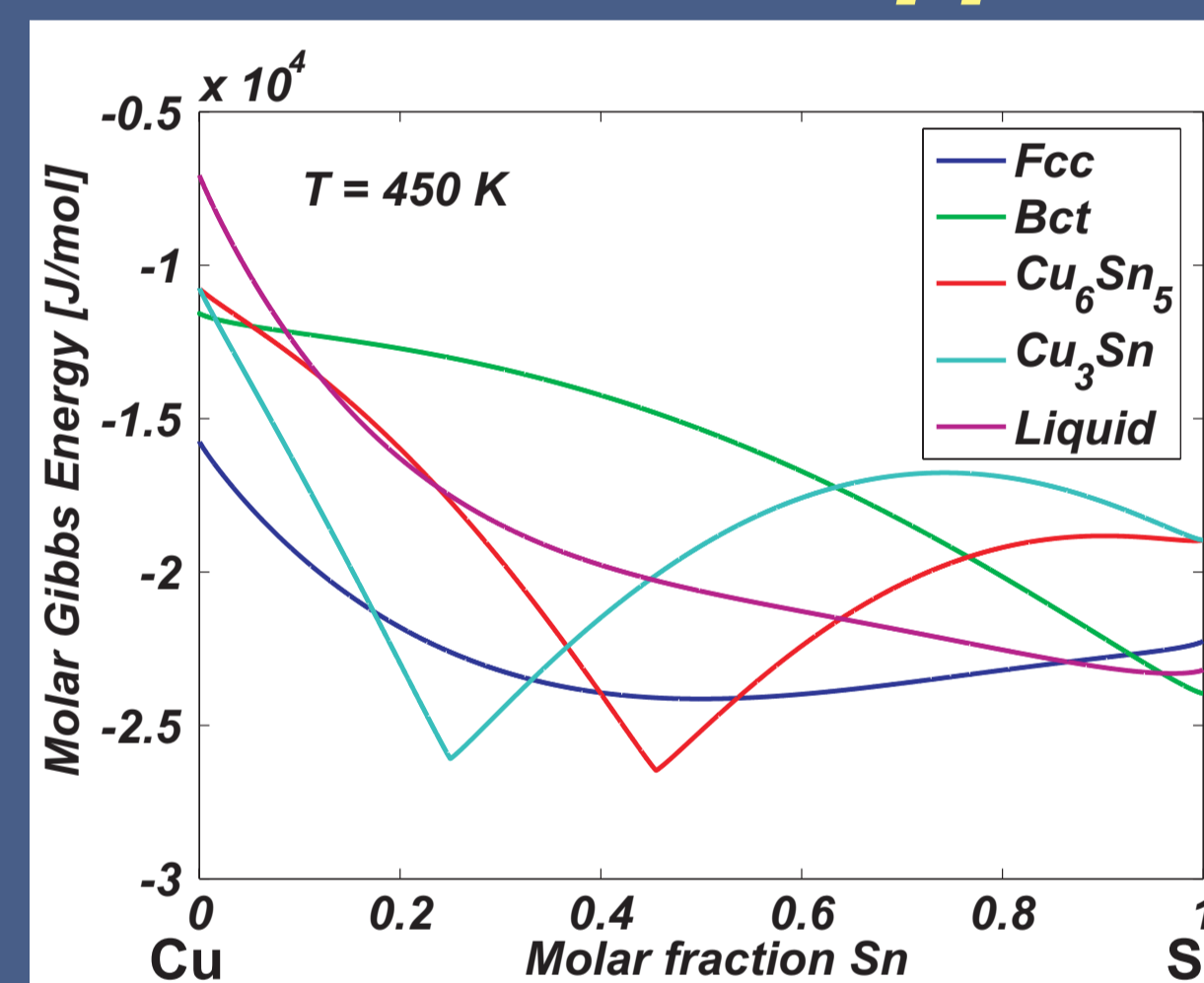
$$V_m f^{stoich} = \frac{A^{stoich}}{2} (x_{Sn} - x_{Sn}^{stoich})^2 + G_m^{stoich}$$

Small shift in composition depending on choice A^{stoich}

$$M^{stoich} = \frac{D^{stoich}}{A^{stoich}}$$

To optimize -- From existing optimization

Order-disorder[4]

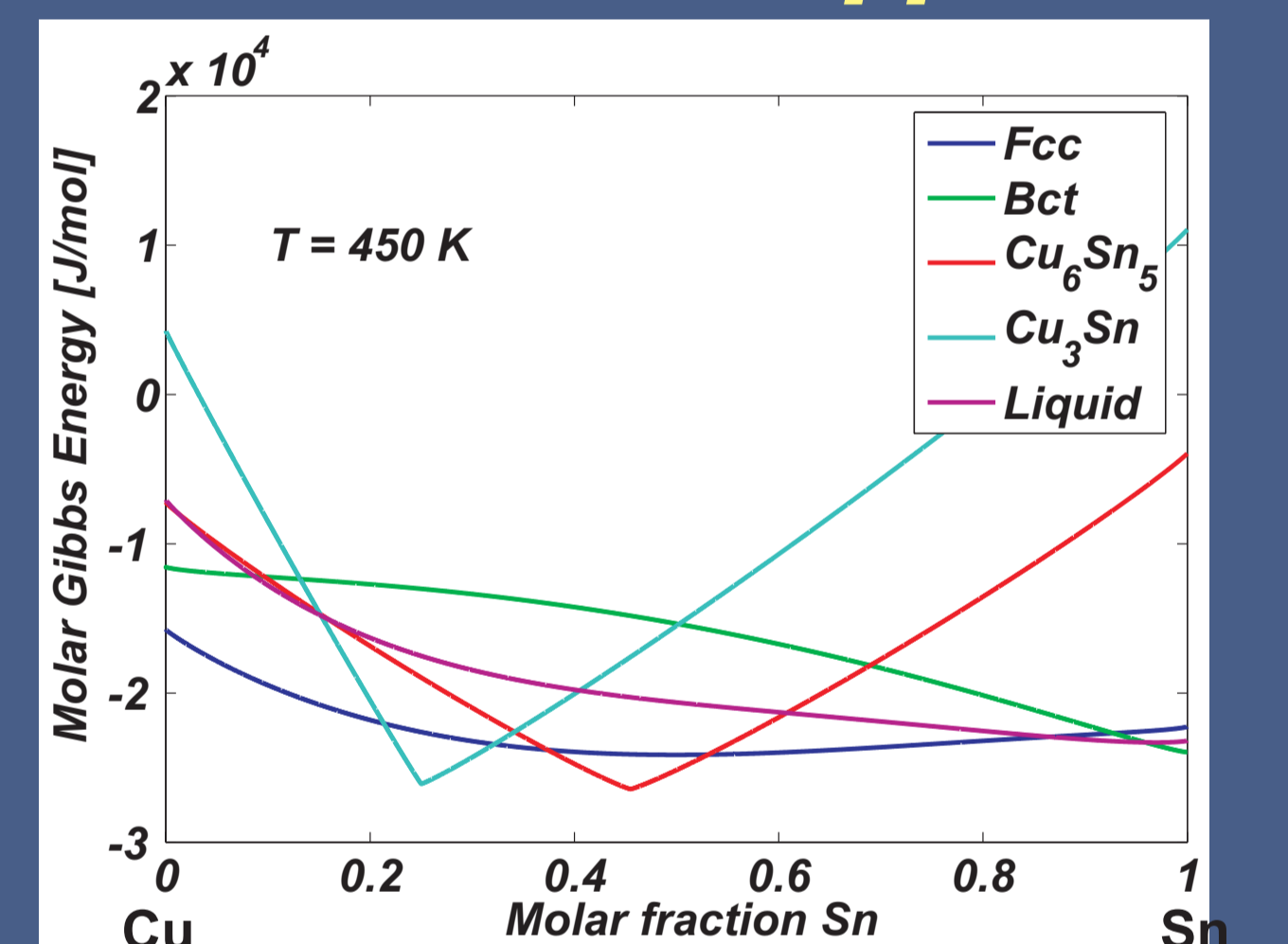


$$G_m^{Cu3Sn} = x_{Cu} G_{Cu}^0 + x_{Sn} G_{Sn}^0 + (y_{Cu}^1 y_{Sn}^2 - x_{Cu} x_{Sn}) G_{CuSn}^{ord} + x_{Cu} x_{Sn} G_{CuSn}^0 + RT[0.75(y_{Cu}^1 \ln(y_{Cu}^1) + y_{Sn}^2 \ln(y_{Sn}^2)) + 0.25(y_{Cu}^2 \ln(y_{Cu}^2) + y_{Sn}^1 \ln(y_{Sn}^1))]$$

with $G_{Ag}^0 = GHSER + 5000$, $L_{Cu,Sn}$, G_{Cu3Sn}^{ord} optimized

Sublattices: $(Cu,Sn)_{0.75}(Cu,Sn)_{0.25}$

Sublattice[5]



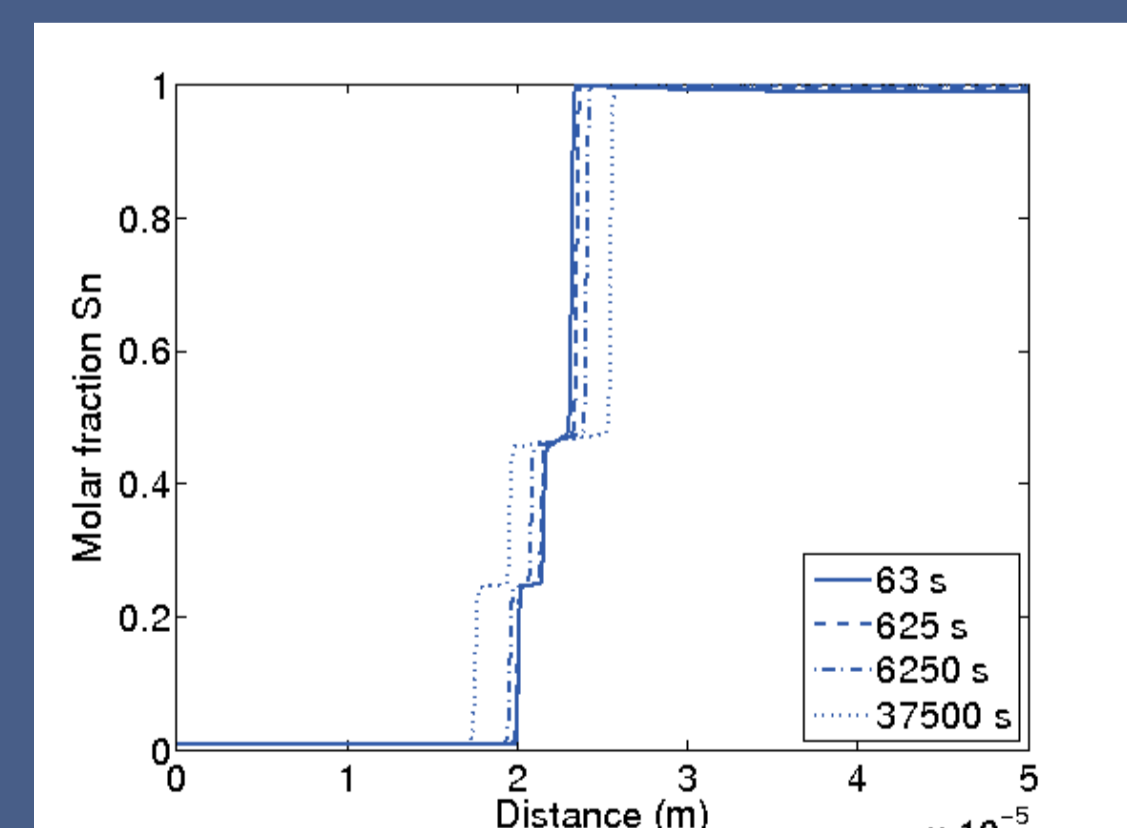
$$G_m^{Cu3Sn} = y_{Cu}^1 y_{Cu}^2 G_{Cu}^0 + y_{Sn}^1 y_{Sn}^2 G_{Sn}^0 + y_{Cu}^1 y_{Sn}^2 G_{Cu3Sn}^0 + y_{Sn}^1 y_{Cu}^2 G_{Sn3Cu}^0 + RT[0.75(y_{Cu}^1 \ln(y_{Cu}^1) + y_{Sn}^1 \ln(y_{Sn}^1)) + 0.25(y_{Cu}^2 \ln(y_{Cu}^2) + y_{Sn}^2 \ln(y_{Sn}^2))]$$

with $G_{Sn3Cu}^0 = G_{Cu}^0 + G_{Sn}^0 - G_{Cu3Sn}^0$

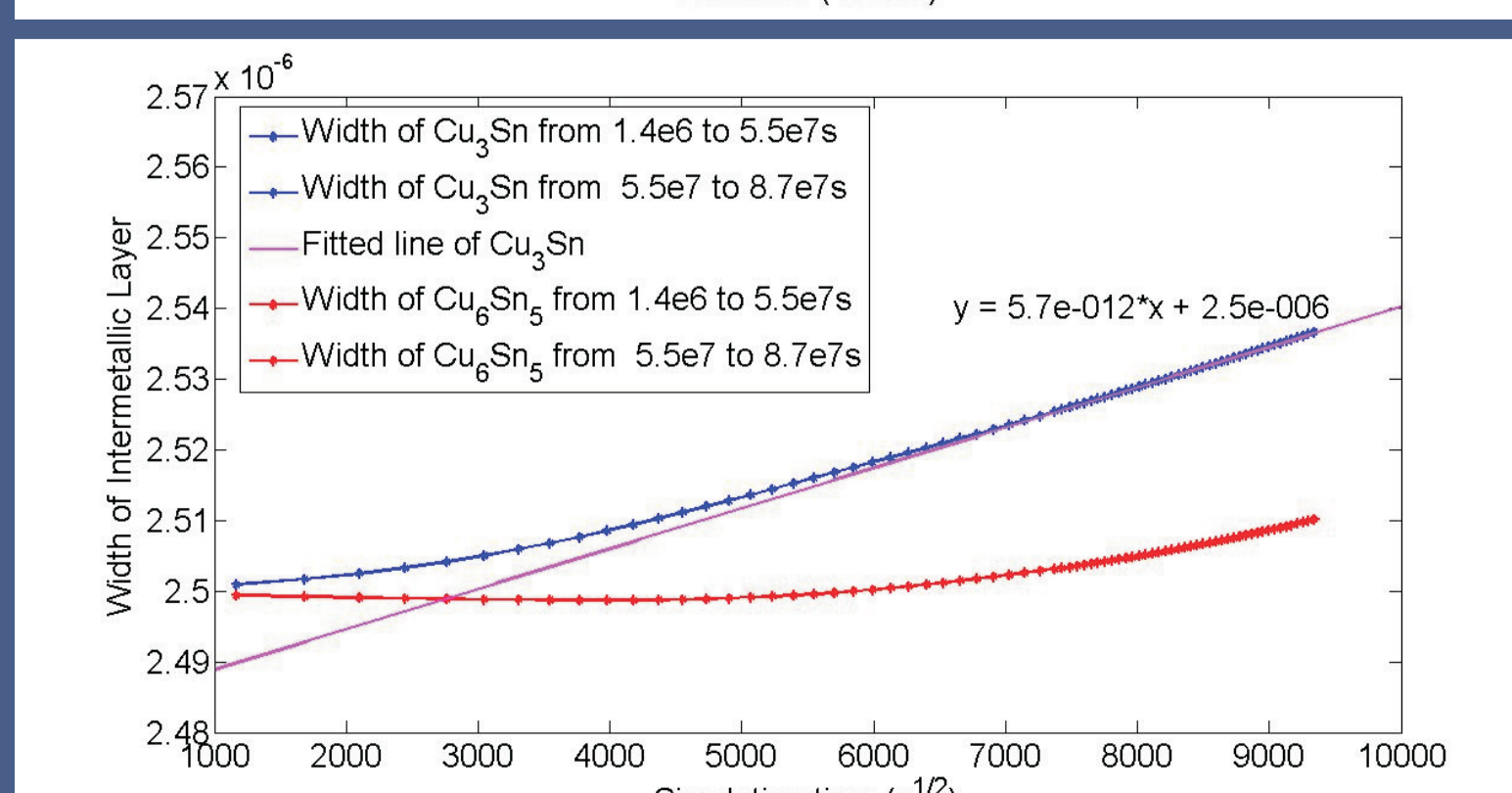
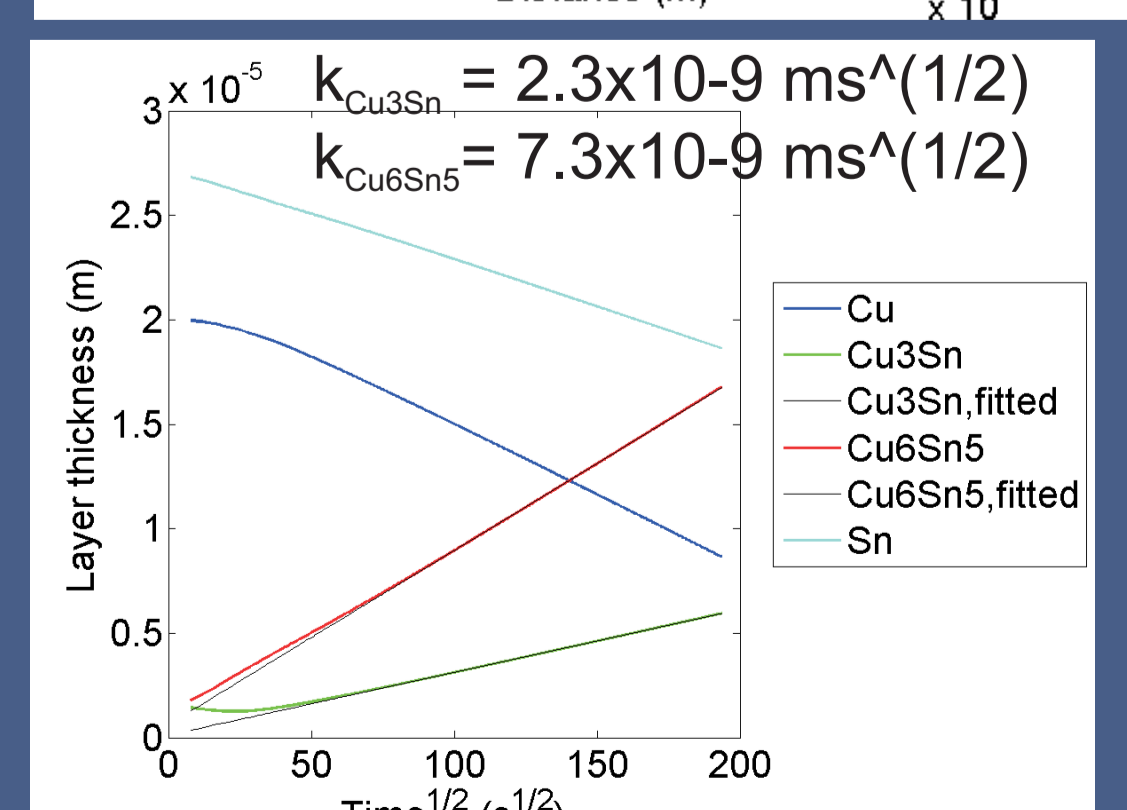
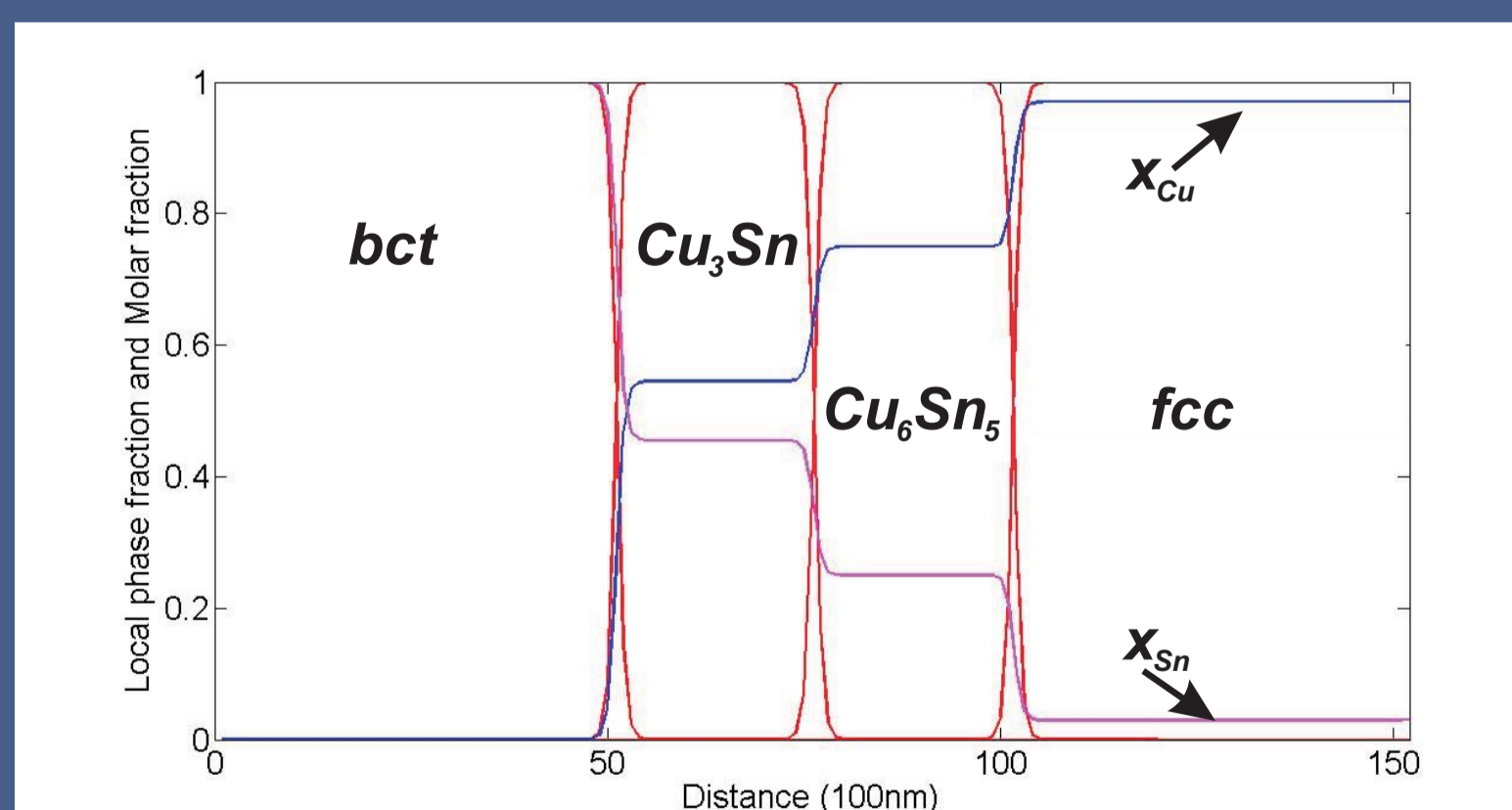
$$M^{Cu3Sn} = \beta^{Cu3Sn} (0.75 y_{Cu}^1 y_{Sn}^1 + 0.25 y_{Cu}^2 y_{Sn}^2) \quad [6]$$

Intermediate phase growth (T=450)

Parabolic



Sublattice



Cu₆Sn₅ grows fastest!

Cu₃Sn grows fastest! [8]

Diffusion mobilities estimated based on interdiffusion data from [7]

Concluding remarks

- Gibbs energy model affects IMC growth behavior and diffusion paths
- The presented approaches can be used with sharp interface models as well
- Order-disorder and sublattice model allow for extrapolation to higher order systems and iterative improvement of the model parameters
- Ab initio calculations are required to optimize the G^0 and G^{ord}

References

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